

## Index-Guided High Power AlGaInP Laser Diode

### Description

The SLD1236VL-54 is an index-guided AlGaInP 650nm laser diode.

### Feature

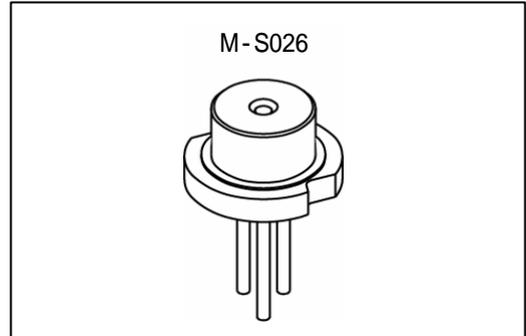
- High power output
- Low power consumption
- Small astigmatism
- Small package (  $\phi$  5.6mm)
- Cavity length 1400  $\mu$  m

### Applications

- Optical pickup for DVD recording and play back

### Structure

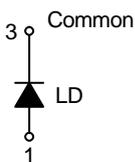
- AlGaInP quantum well structured laser diode



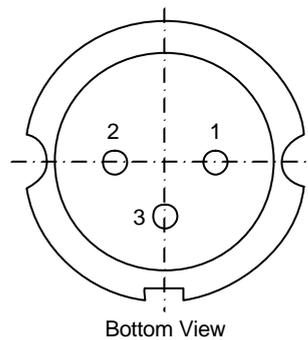
### Absolute Maximum Ratings

- |                         |       |              |                          |
|-------------------------|-------|--------------|--------------------------|
| • Radiant power output  | Po    | 90           | mW(CW)                   |
|                         |       | 180          | mW(Pulse)                |
|                         |       |              | Pulse width 30ns or less |
|                         |       |              | Duty 40% or less         |
| • Reverse voltage       | VR LD | 2            | V                        |
| • Operating temperature | Topr  | - 10 to + 75 |                          |
| • Storage temperature   | Tstg  | - 40 to + 85 |                          |

### Connection Diagram



### Pin Configuration



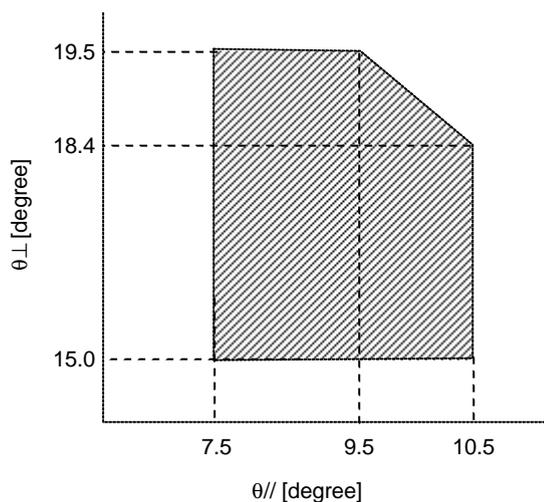
1. LD anode
2. N.C.
3. Common

Electrical and Optical Characteristics (Tc=25 )

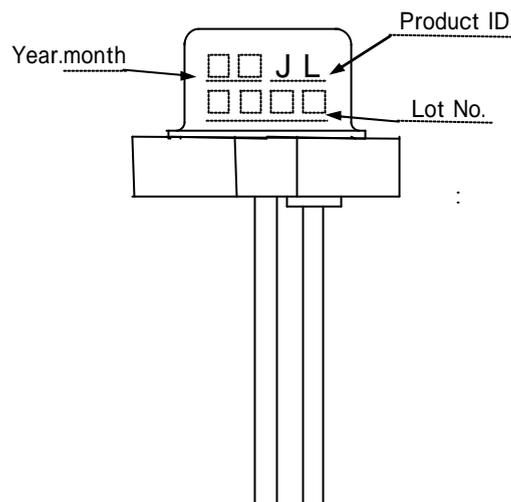
Tc:Case temperature

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Threshold current	I <sub>th</sub>	CW	-	50	60	mA
Operating current	I <sub>op</sub>	CW, P <sub>o</sub> = 80mW	-	130	150	mA
Operating voltage	V <sub>op</sub>	CW, P <sub>o</sub> = 80mW	-	2.5	3.0	V
Wavelength	λ	CW, P <sub>o</sub> = 80mW	653	658	662	nm
Differential efficiency	η <sub>D</sub>	CW, P <sub>o</sub> = 80mW	0.75	1.0	1.25	mW/mA
Radiation angle	Parallel	CW, P <sub>o</sub> = 80mW	7.5	9.0	10.5	degree
	Perpendicular	CW, P <sub>o</sub> = 80mW	15.0	17.0	19.5	degree
	Sum of radiation angles	1.2 + CW, P <sub>o</sub> = 80mW	-	-	31.0	degree
Astigmatism	As	CW, P <sub>o</sub> = 80mW	-6	-	0	μm
Positional accuracy	Angle	CW, P <sub>o</sub> = 80mW	-	-	± 1.6	degree
		CW, P <sub>o</sub> = 80mW	-	-	± 2.5	degree
	Position	X, Y, Z	-	-	± 80	μm

Radiation angle (CW,Po=80mW)



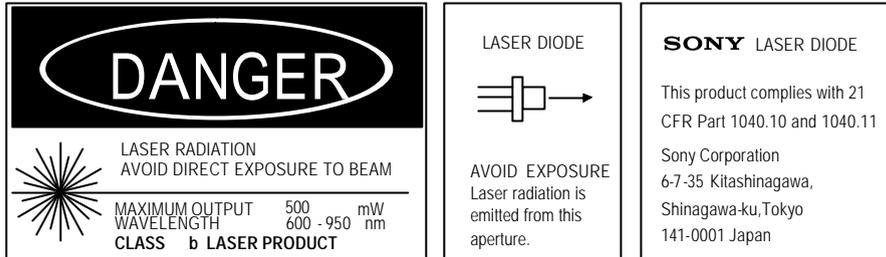
Marking



**Notes on Operation**

Care should be taken for the following points When using this product.

- (1) This product corresponds to a Class 3B product under IEC 60825-1 .



- (2) Eye protection against laser beams

Take care not to allow laser beams to enter your eyes under any circumstances.

For observing laser beams ALWAYS use Safety goggles that block laser beams. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

- (3) Gallium Arsenide

This product uses gallium arsenide (GaAs). This is not a problem for normal use, but GaAs vapors may be potentially hazardous to the human body. Therefore, never crush, heat to the maximum storage temperature or higher, or place the product in your mouth.

In addition, the following disposal methods are recommended when disposing of this product.

1. Engaging the services of a contractor certified in the collection, transport and intermediate treatment of items containing arsenic.
2. Managing the product through to final disposal as specially managed industrial waste which is handled separately from general industrial waste and household waste.

- (4) Prevention of surge current and electrostatic discharge

Laser diodes are most sensitive to electrostatic discharge among semiconductors. When a large current is passed through the laser diode for even an extremely short time, the strong light emitted from the laser diode promotes deterioration and then destruction of the laser diode. Therefore, note that surge current should not flow to the laser diode driving circuit from switches and others. Also, if the laser diode is handled carelessly, it may be destroyed instantly because electrostatic discharge is easily applied by a human body. Therefore, be extremely careful about overcurrent and electrostatic discharge.

Also, use the power supply that was designed not to exceed the optical power output specified at the absolute maximum ratings.

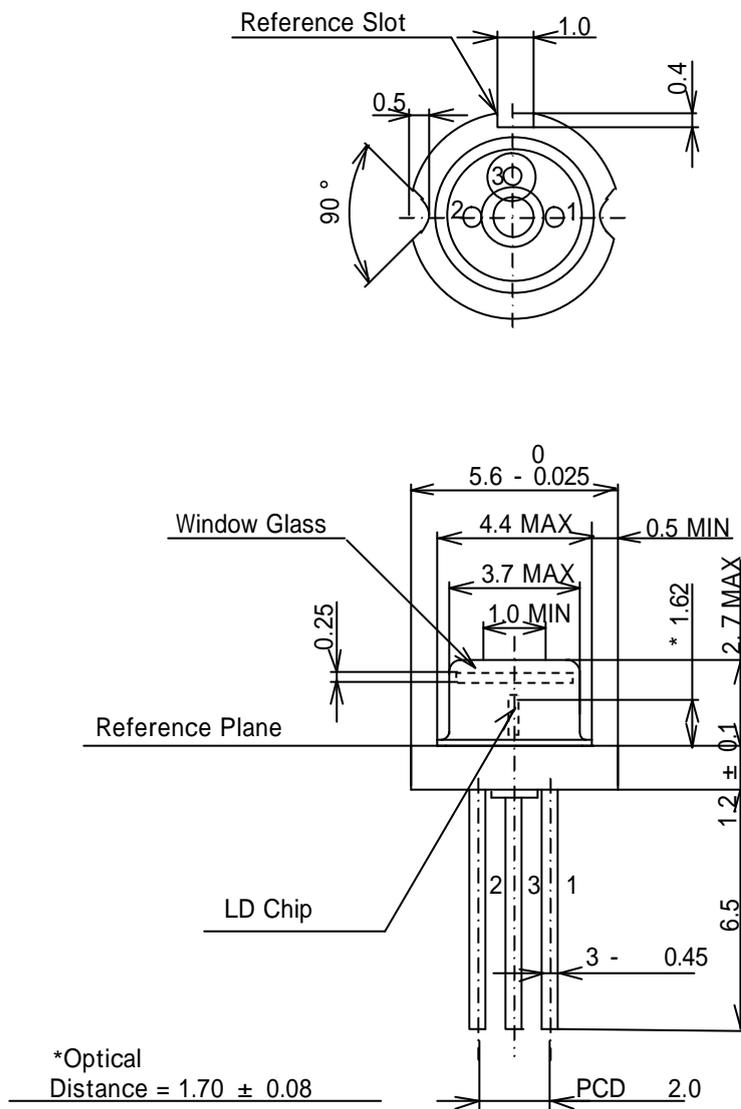
- (5) Use for special applications

This product is not designed or manufactured for use in equipment used under circumstances where failure may pose a risk to life and limb, or result in significant material damage, etc.

Consult your Sony sales representative when investigating use for medical, vehicle, nuclear power control or other special applications.

Package Outline Unit: mm

M-S026



SONY CODE	
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE MASS	0.3g
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Sony Corporation